

# Hyperfast Rectifier, 1 A FRED Pt®

## eSMP® Series



Top view

Bottom view

**SMF (DO-219AB)**

Cathode  Anode

## LINKS TO ADDITIONAL RESOURCES



3D Models

## PRIMARY CHARACTERISTICS

|                              |                |
|------------------------------|----------------|
| $I_{F(AV)}$                  | 1 A            |
| $V_R$                        | 200 V          |
| $V_F$ at $I_F$ (typ. 125 °C) | 0.74 V         |
| $t_{rr}$                     | 25 ns          |
| $T_J$ max.                   | 175 °C         |
| Package                      | SMF (DO-219AB) |
| Circuit configuration        | Single         |

## FEATURES

- Hyperfast recovery time, reduced  $Q_{rr}$ , and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Wave and reflow solderable
- Compatible to SOD-123W package case outline
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

## DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber boost, lighting, piezo-injection, as high frequency rectifiers, and freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

## MECHANICAL DATA

**Case:** SMF (DO-219AB)

Molding compound meets UL 94 V-0 flammability rating  
Halogen-free, RoHS-compliant

**Terminals:** matte tin plated leads, solderable per J-STD-002

**Polarity:** color band denotes cathode end

## ABSOLUTE MAXIMUM RATINGS

| PARAMETER                                        | SYMBOL         | TEST CONDITIONS             | VALUES      | UNITS |
|--------------------------------------------------|----------------|-----------------------------|-------------|-------|
| Peak repetitive reverse voltage                  | $V_{RRM}$      |                             | 200         | V     |
| Average rectified forward current                | $I_{F(AV)}$    | $T_C = 160\text{ °C}^{(1)}$ | 1           | A     |
| Non-repetitive peak surge current                | $I_{FSM}$      | $T_J = 25\text{ °C}$        | 35          |       |
| Operating junction and storage temperature range | $T_J, T_{Stg}$ |                             | -65 to +175 | °C    |

### Note

<sup>(1)</sup> Device on PCB with 8 mm x 16 mm soldering lands

**ELECTRICAL SPECIFICATIONS** ( $T_J = 25\text{ }^{\circ}\text{C}$  unless otherwise specified)

| PARAMETER                           | SYMBOL        | TEST CONDITIONS                                             | MIN. | TYP. | MAX. | UNITS         |
|-------------------------------------|---------------|-------------------------------------------------------------|------|------|------|---------------|
| Breakdown voltage, blocking voltage | $V_{BR}, V_R$ | $I_R = 100\text{ }\mu\text{A}$                              | 200  | -    | -    | V             |
| Forward voltage                     | $V_F$         | $I_F = 1\text{ A}$                                          | -    | 0.87 | 0.93 |               |
|                                     |               | $I_F = 1\text{ A}, T_J = 125\text{ }^{\circ}\text{C}$       | -    | 0.74 | 0.8  |               |
| Reverse leakage current             | $I_R$         | $V_R = V_R\text{ rated}$                                    | -    | -    | 2    | $\mu\text{A}$ |
|                                     |               | $T_J = 125\text{ }^{\circ}\text{C}, V_R = V_R\text{ rated}$ | -    | 0.5  | 8    |               |
| Junction capacitance                | $C_T$         | $V_R = 200\text{ V}$                                        | -    | 5    | -    | pF            |

**DYNAMIC RECOVERY CHARACTERISTICS** ( $T_J = 25\text{ }^{\circ}\text{C}$  unless otherwise specified)

| PARAMETER               | SYMBOL    | TEST CONDITIONS                                                          | MIN. | TYP. | MAX. | UNITS |
|-------------------------|-----------|--------------------------------------------------------------------------|------|------|------|-------|
| Reverse recovery time   | $t_{rr}$  | $I_F = 1\text{ A}, dI_F/dt = 50\text{ A}/\mu\text{s}, V_R = 30\text{ V}$ | -    | 24   | -    | ns    |
|                         |           | $I_F = 0.5\text{ A}, I_R = 1\text{ A}, I_{rr} = 0.25\text{ A}$           | -    | -    | 25   |       |
|                         |           | $T_J = 25\text{ }^{\circ}\text{C}$                                       | -    | 16   | -    |       |
|                         |           | $T_J = 125\text{ }^{\circ}\text{C}$                                      | -    | 23   | -    |       |
| Peak recovery current   | $I_{RRM}$ | $T_J = 25\text{ }^{\circ}\text{C}$                                       | -    | 1.6  | -    | A     |
|                         |           | $T_J = 125\text{ }^{\circ}\text{C}$                                      | -    | 2.5  | -    |       |
| Reverse recovery charge | $Q_{rr}$  | $T_J = 25\text{ }^{\circ}\text{C}$                                       | -    | 13   | -    | nC    |
|                         |           | $T_J = 125\text{ }^{\circ}\text{C}$                                      | -    | 30   | -    |       |

**THERMAL - MECHANICAL SPECIFICATIONS**

| PARAMETER                                      | SYMBOL         | TEST CONDITIONS                                          | MIN.   | TYP. | MAX. | UNITS                       |
|------------------------------------------------|----------------|----------------------------------------------------------|--------|------|------|-----------------------------|
| Maximum junction and storage temperature range | $T_J, T_{Stg}$ |                                                          | -65    | -    | +175 | $^{\circ}\text{C}$          |
| Thermal resistance, junction to mount          | $R_{thJM}$     | Device mounted on PCB with 8 mm x 16 mm soldering lands  | -      | -    | 17   | $^{\circ}\text{C}/\text{W}$ |
| Thermal resistance, junction to ambient        | $R_{thJA}$     | Device mounted on PCB with 2 mm x 3.5 mm soldering lands | -      | -    | 140  | $^{\circ}\text{C}/\text{W}$ |
| Approximate weight                             |                |                                                          | 0.015  |      |      | g                           |
|                                                |                |                                                          | 0.0005 |      |      | oz.                         |
| Marking device                                 |                | Case style SMF (DO-219AB)                                | MDH    |      |      |                             |

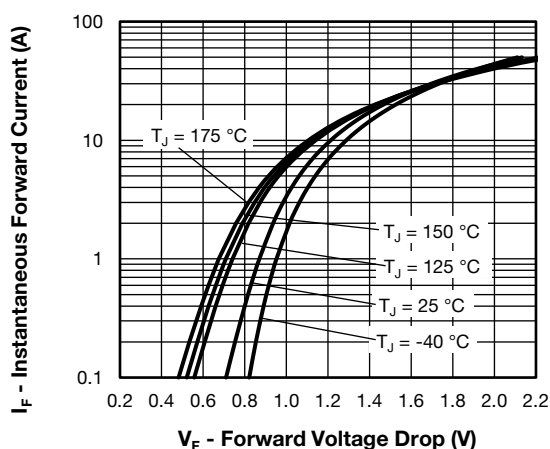


Fig. 1 - Typical Forward Voltage Drop Characteristics

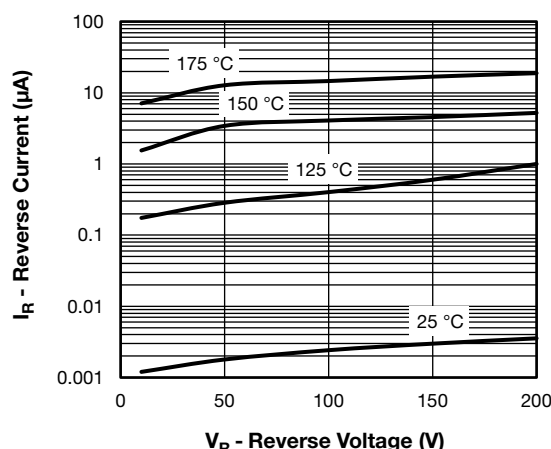


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

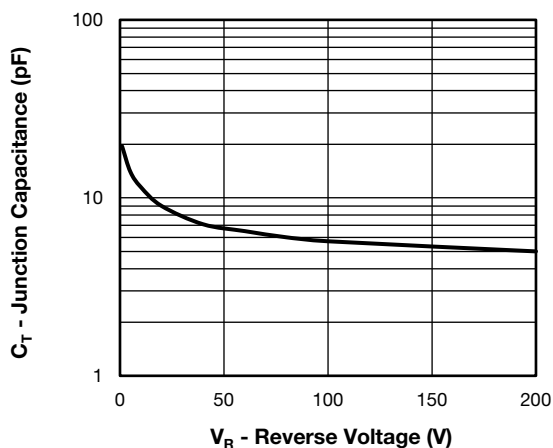


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

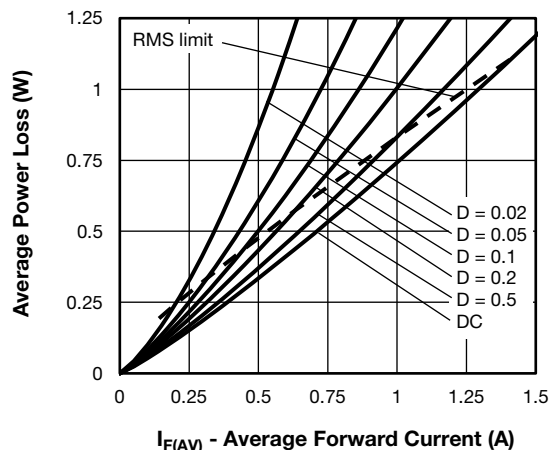


Fig. 5 - Forward Power Loss Characteristics

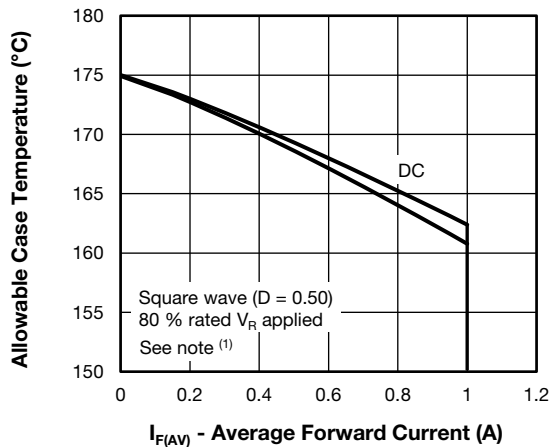
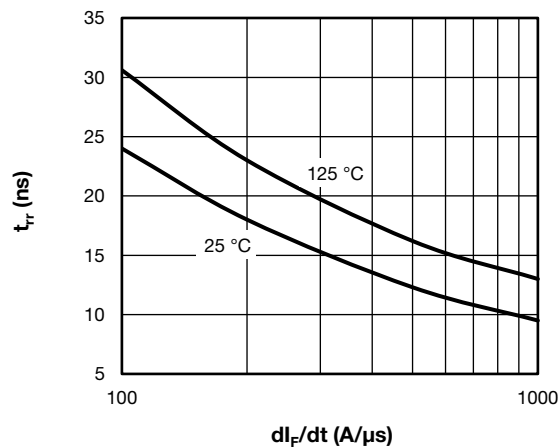
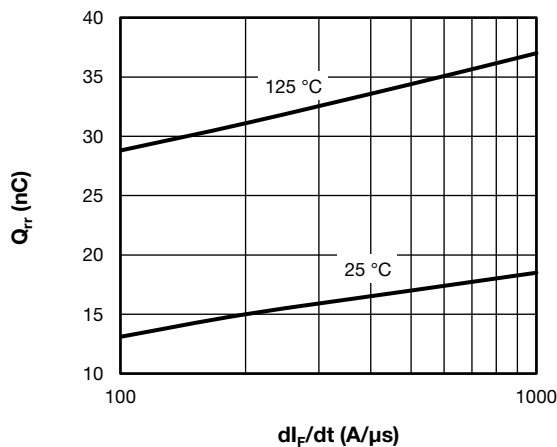


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current


Fig. 6 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

Fig. 7 - Typical Stored Charge vs.  $dI_F/dt$ 

#### Note

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 5);  
 $P_{dREV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$

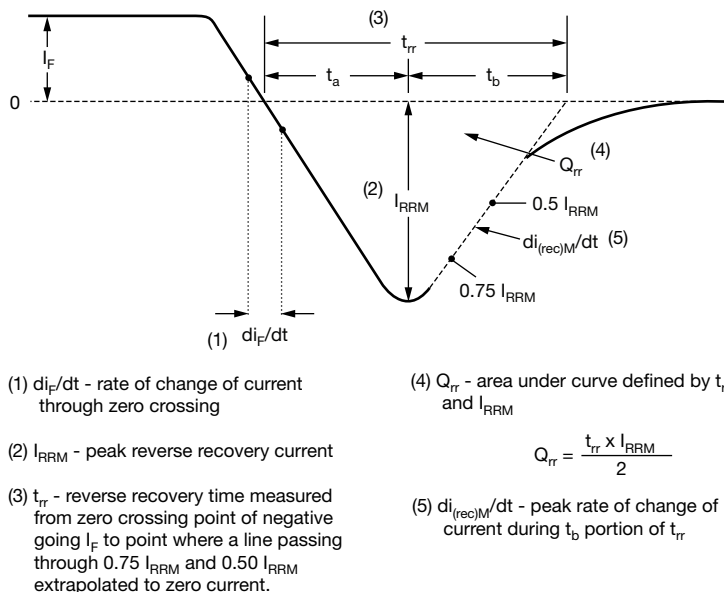


Fig. 8 - Reverse Recovery Waveform and Definitions

## ORDERING INFORMATION TABLE

| Device code | VS- | 1 | E | F | H | 02 | H | M3 |
|-------------|-----|---|---|---|---|----|---|----|
|             | 1   | 2 | 3 | 4 | 5 | 6  | 7 | 8  |

- 1** - Vishay Semiconductors product
- 2** - Current rating (1 = 1 A)
- 3** - Circuit configuration:  
E = single diode
- 4** - F = SMF package
- 5** - Process type,  
H = hyperfast recovery
- 6** - Voltage code (02 = 200 V)
- 7** - H = AEC-Q101 qualified
- 8** - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

## ORDERING INFORMATION (Example)

| PREFERRED P/N  | QUANTITY PER REEL | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION              |
|----------------|-------------------|------------------------|------------------------------------|
| VS-1EFH02HM3/I | 10 000            | 10 000                 | 13" diameter plastic tape and reel |

## LINKS TO RELATED DOCUMENTS

|                          |                                                                        |
|--------------------------|------------------------------------------------------------------------|
| Dimensions               | <a href="http://www.vishay.com/doc?95572">www.vishay.com/doc?95572</a> |
| Part marking information | <a href="http://www.vishay.com/doc?95618">www.vishay.com/doc?95618</a> |
| Packaging information    | <a href="http://www.vishay.com/doc?95577">www.vishay.com/doc?95577</a> |
| SPICE model              | <a href="http://www.vishay.com/doc?96012">www.vishay.com/doc?96012</a> |



## SMF (DO-219AB)

**DIMENSIONS** in millimeters (inches)



Foot print recommendation:



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17247



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